## LMH6642EP/LMH6643EP/LMH6644EP Enhanced Plastic Low Power, 130MHz, 75mA Rail-to-Rail Output Amplifiers

## General Description

The LMH664XEP family true single supply voltage feedback amplifiers offer high speed (130MHz), low distortion ( -62 dBc ), and exceptionally high output current (approximately 75 mA ) at low cost and with reduced power consumption when compared against existing devices with similar performance.
Input common mode voltage range extends to 0.5 V below $\mathrm{V}^{-}$ and 1 V from $\mathrm{V}^{+}$. Output voltage range extends to within 40 mV of either supply rail, allowing wide dynamic range especially desirable in low voltage applications. The output stage is capable of approximately 75 mA in order to drive heavy loads. Fast output Slew Rate ( $130 \mathrm{~V} / \mathrm{\mu s}$ ) ensures large peak-to-peak output swings can be maintained even at higher speeds, resulting in exceptional full power bandwidth of 40 MHz with a 3 V supply. These characteristics, along with low cost, are ideal features for a multitude of industrial and commercial applications.
Careful attention has been paid to ensure device stability under all operating voltages and modes. The result is a very well behaved frequency response characteristic $(0.1 \mathrm{~dB}$ gain flatness up the 12 MHz under $150 \Omega$ load and $A_{V}=+2$ ) with minimal peaking (typically 2 dB maximum) for any gain setting and under both heavy and light loads. This along with fast settling time ( 68 ns ) and low distortion allows the device to operate well in ADC buffer, and high frequency filter applications as well as other applications.
This device family offers professional quality video performance with low DG $(0.01 \%)$ and DP $\left(0.01^{\circ}\right)$ characteristics. Differential Gain and Differential Phase characteristics are also well maintained under heavy loads (150 $\Omega$ ) and throughout the output voltage range. The LMH664XEP family is offered in single (LMH6642EP), dual (LMH6643EP), and quad (LMH6644EP) options. See ordering information for packages offered.

## ENHANCED PLASTIC

- Extended Temperature Performance of $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
- Baseline Control - Single Fab \& Assembly Site
- Process Change Notification (PCN)
- Qualification \& Reliability Data
- Solder (PbSn) Lead Finish is standard
- Enhanced Diminishing Manufacturing Sources (DMS) Support


## Features

$\left(\mathrm{V}_{\mathrm{S}}= \pm 5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{A}_{\mathrm{V}}=+1\right.$. Typical values unless specified).

- -3 dB BW $\left(\mathrm{A}_{\mathrm{V}}=+1\right)$

130 MHz

- Supply voltage range 2.7 V to 12.8 V
- Slew rate (Note 11), $\left(A_{V}=-1\right)$ 130V/us
- Supply current (no load) $2.7 \mathrm{~mA} / \mathrm{amp}$
- Output short circuit current $+115 \mathrm{~mA} /-145 \mathrm{~mA}$
- Linear output current $\pm 75 \mathrm{~mA}$
- Input common mode volt. 0.5 V beyond $\mathrm{V}^{-}, 1 \mathrm{~V}$ from $\mathrm{V}^{+}$
- Output voltage swing 40 mV from rails
- Input voltage noise (100kHz) $17 n \mathrm{~V} / \sqrt{\mathrm{Hz}}$
- Input current noise (100kHz) $0.9 \mathrm{pA} / \sqrt{\mathrm{Hz}}$
- THD ( $5 \mathrm{MHz}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}_{\mathrm{PP}}, \mathrm{A}_{\mathrm{V}}=+2$ ) $\quad-62 \mathrm{dBc}$
- Settling time

68ns

- Fully characterized for $3 \mathrm{~V}, 5 \mathrm{~V}$, and $\pm 5 \mathrm{~V}$
- Overdrive recovery

100ns

- Output short circuit protected (Note 14)
- No output phase reversal with CMVR exceeded


## Applications

- Selected Military Applications
- Selected Avionics Applications


## Ordering Information

| PART NUMBER | VID PART NUMBER | NS PACKAGE NUMBER (Note 3) |
| :--- | :--- | :--- |
| LMH6642MFXEP | V62/04625-01 | MF05A |
| LMH6643MAXEP | V62/04625-02 | M08A |
| LMH6644MAXEP | V62/04625-03 | M14A |
| (Notes 1, 2) | TBD | TBD |

Note 1: For the following (Enhanced Plastic) versions, check for availability: LMH6642MAEP, LMH6642MAXEP, LMH6642MFEP, LMH6643MAEP, LMH6643MMEP, LMH6643MMXEP, LMH6644MAEP, LMH6644MTEP, LMH6644MTXEP. Parts listed with an "X" are provided in Tape \& Reel and parts without an "X" are in Rails.
Note 2: FOR ADDITIONAL ORDERING AND PRODUCT INFORMATION, PLEASE VISIT THE ENHANCED PLASTIC WEB SITE AT: www.national.com/ mil
Note 3: Refer to package details under Physical Dimensions

Absolute Maximum Ratings (Note 4)
If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

ESD Tolerance
$\mathrm{V}_{\mathrm{IN}}$ Differential
Output Short Circuit Duration
Supply Voltage ( $\mathrm{V}^{+}-\mathrm{V}^{-}$)
Voltage at Input/Output pins
Input Current
Storage Temperature Range
Junction Temperature (Note 7)
Soldering Information

2KV (Note 5) 200V (Note 12)
(Note 6), (Note 14)
13.5 V
$\mathrm{V}^{+}+0.8 \mathrm{~V}, \mathrm{~V}^{-}-0.8 \mathrm{~V}$
$\pm 10 \mathrm{~mA}$
$-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
$+150^{\circ} \mathrm{C}$

Infrared or Convection Reflow(20 sec)
$235^{\circ} \mathrm{C}$
Wave Soldering Lead Temp. $(10 \mathrm{sec})$

## Operating Ratings (Note 4)

| Supply Voltage $\left(\mathrm{V}^{+}-\mathrm{V}^{-}\right)$ | 2.7 V to 12.8 V |
| :--- | ---: |
| Junction Temperature Range (Note 7) | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Package Thermal Resistance (Note 7) $\left(\theta_{\mathrm{JA}}\right)$ |  |
| SOT23-5 | $265^{\circ} \mathrm{C} / \mathrm{W}$ |
| SOIC-8 | $190^{\circ} \mathrm{C} / \mathrm{W}$ |
| MSOP-8 | $235^{\circ} \mathrm{C} / \mathrm{W}$ |
| SOIC-14 | $145^{\circ} \mathrm{C} / \mathrm{W}$ |
| TSSOP-14 | $155^{\circ} \mathrm{C} / \mathrm{W}$ |

## 3V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for at $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=3 \mathrm{~V}, \mathrm{~V}^{-}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{O}}=\mathrm{V}^{+} / 2$, and $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$. Boldface limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | $\begin{gathered} \text { Min } \\ \text { (Note 9) } \end{gathered}$ | $\begin{aligned} & \text { Typ } \\ & \text { (Note 8) } \end{aligned}$ | $\begin{gathered} \text { Max } \\ (\text { Note } 9) \end{gathered}$ | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BW | -3dB BW | $\mathrm{A}_{\mathrm{V}}=+1, \mathrm{~V}_{\text {OUT }}=200 \mathrm{mV} \mathrm{PP}$ | 80 | 115 |  | MHz |
|  |  | $\mathrm{A}_{\mathrm{V}}=+2,-1, \mathrm{~V}_{\text {OUT }}=200 \mathrm{mV} \mathrm{VPP}$ |  | 46 |  |  |
| $\mathrm{BW}_{0.1 \mathrm{~dB}}$ | 0.1dB Gain Flatness | $\begin{aligned} & \hline \mathrm{A}_{\mathrm{V}}=+2, \mathrm{R}_{\mathrm{L}}=150 \Omega \text { to } \mathrm{V}+/ 2, \\ & \mathrm{R}_{\mathrm{L}}=402 \Omega, \mathrm{~V}_{\text {OUT }}=200 \mathrm{mV}_{\mathrm{PP}} \\ & \hline \end{aligned}$ |  | 19 |  | MHz |
| PBW | Full Power Bandwidth | $\mathrm{A}_{\mathrm{V}}=+1,-1 \mathrm{~dB}, \mathrm{~V}_{\text {OUT }}=1 \mathrm{~V}_{\text {PP }}$ |  | 40 |  | MHz |
| $\mathrm{e}_{\mathrm{n}}$ | Input-Referred Voltage Noise | $\mathrm{f}=100 \mathrm{kHz}$ |  | 17 |  | $\mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
|  |  | $\mathrm{f}=1 \mathrm{kHz}$ |  | 48 |  |  |
| $i_{n}$ | Input-Referred Current Noise | $\mathrm{f}=100 \mathrm{kHz}$ |  | 0.90 |  | $\mathrm{pA} / \sqrt{\mathrm{Hz}}$ |
|  |  | $\mathrm{f}=1 \mathrm{kHz}$ |  | 3.3 |  |  |
| THD | Total Harmonic Distortion | $\begin{aligned} & \mathrm{f}=5 \mathrm{MHz}, \mathrm{~V}_{\mathrm{O}}=2 \mathrm{~V}_{\mathrm{PP}}, \mathrm{~A}_{\mathrm{V}}=-1, \\ & \mathrm{R}_{\mathrm{L}}=100 \Omega \text { to } \mathrm{V}^{+} / 2 \end{aligned}$ |  | -48 |  | dBc |
| DG | Differential Gain | $\begin{aligned} \mathrm{V}_{\mathrm{CM}} & =1 \mathrm{~V}, \mathrm{NTSC}, \mathrm{~A}_{\mathrm{V}}=+2 \\ \mathrm{R}_{\mathrm{L}} & =150 \Omega \text { to } \mathrm{V}^{+} / 2 \end{aligned}$ |  | 0.17 |  | \% |
|  |  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$ |  | 0.03 |  |  |
| DP | Differential Phase | $\begin{aligned} \mathrm{V}_{\mathrm{CM}} & =1 \mathrm{~V}, \mathrm{NTSC}, \mathrm{~A}_{\mathrm{V}}=+2 \\ \mathrm{R}_{\mathrm{L}} & =150 \Omega \text { to } \mathrm{V}^{+} / 2 \end{aligned}$ |  | 0.05 |  | deg |
|  |  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$ |  | 0.03 |  |  |
| CT Rej. | Cross-Talk Rejection | $\mathrm{f}=5 \mathrm{MHz}$, Receiver: $\mathrm{R}_{\mathrm{f}}=\mathrm{R}_{\mathrm{g}}=510 \Omega, \mathrm{~A}_{\mathrm{V}}=+2$ |  | 47 |  | dB |
| $\mathrm{T}_{\mathrm{S}}$ | Settling Time | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}_{\mathrm{PP}}, \pm 0.1 \%, 8 \mathrm{pF} \text { Load, } \\ & \mathrm{V}_{\mathrm{S}}=5 \mathrm{~V} \end{aligned}$ |  | 68 |  | ns |
| SR | Slew Rate (Note 11) | $\mathrm{A}_{\mathrm{V}}=-1, \mathrm{~V}_{1}=2 \mathrm{~V}_{\mathrm{PP}}$ | 90 | 120 |  | V/us |
| $\mathrm{V}_{\text {OS }}$ | Input Offset Voltage |  |  | $\pm 1$ | $\begin{aligned} & \pm 5 \\ & \pm 7 \end{aligned}$ | mV |
| TC V ${ }_{\text {OS }}$ | Input Offset Average Drift | (Note 15) |  | $\pm 5$ |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | (Note 10) |  | -1.50 | $\begin{aligned} & \hline-2.60 \\ & -3.25 \end{aligned}$ | $\mu \mathrm{A}$ |
| los | Input Offset Current |  |  | 20 | $\begin{gathered} 800 \\ 1000 \end{gathered}$ | nA |
| $\mathrm{R}_{\text {IN }}$ | Common Mode Input Resistance |  |  | 3 |  | $\mathrm{M} \Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Common Mode Input Capacitance |  |  | 2 |  | pF |

## 3V Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for at $T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=3 \mathrm{~V}, \mathrm{~V}^{-}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{O}}=\mathrm{V}^{+} / 2$, and $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$. Boldface limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | $\begin{gathered} \text { Min } \\ (\text { Note 9) } \end{gathered}$ | $\begin{gathered} \text { Typ } \\ \text { (Note 8) } \end{gathered}$ | $\begin{gathered} \text { Max } \\ (\text { Note } 9) \end{gathered}$ | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CMVR | Input Common-Mode Voltage Range | CMRR $\geq 50 \mathrm{~dB}$ |  | -0.5 | $\begin{aligned} & -0.2 \\ & -0.1 \end{aligned}$ | V |
|  |  |  | $\begin{aligned} & 1.8 \\ & 1.6 \end{aligned}$ | 2.0 |  |  |
| CMRR | Common Mode Rejection Ratio | $\mathrm{V}_{\mathrm{CM}}$ Stepped from 0V to 1.5V | 72 | 95 |  | dB |
| $\mathrm{A}_{\text {VOL }}$ | Large Signal Voltage Gain | $\begin{array}{\|l} \hline \mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { to } 2.5 \mathrm{~V} \\ \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega \text { to } \mathrm{V}^{+} / 2 \\ \hline \end{array}$ | $\begin{aligned} & 80 \\ & 75 \end{aligned}$ | 96 |  | dB |
|  |  | $\begin{array}{\|l} \hline \mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { to } 2.5 \mathrm{~V} \\ \mathrm{R}_{\mathrm{L}}=150 \Omega \text { to } \mathrm{V}^{+} / 2 \\ \hline \end{array}$ | $\begin{aligned} & 74 \\ & 70 \\ & \hline \end{aligned}$ | 82 |  |  |
| $\mathrm{V}_{\mathrm{O}}$ | Output Swing High | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2, \mathrm{~V}_{\text {ID }}=200 \mathrm{mV}$ | 2.90 | 2.98 |  | V |
|  |  | $\mathrm{R}_{\mathrm{L}}=150 \Omega$ to $\mathrm{V}^{+} / 2, \mathrm{~V}_{\text {ID }}=200 \mathrm{mV}$ | 2.80 | 2.93 |  |  |
|  | Output Swing Low | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2, \mathrm{~V}_{\text {ID }}=-200 \mathrm{mV}$ |  | 25 | 75 | mV |
|  |  | $\mathrm{R}_{\mathrm{L}}=150 \Omega$ to $\mathrm{V}^{+} / 2, \mathrm{~V}_{\text {ID }}=-200 \mathrm{mV}$ |  | 75 | 150 |  |
| $\mathrm{I}_{\mathrm{sc}}$ | Output Short Circuit Current | Sourcing to $\mathrm{V}^{+} / 2$ $\mathrm{V}_{\mathrm{ID}}=200 \mathrm{mV}(\text { Note } 13)$ | $\begin{aligned} & 50 \\ & 35 \end{aligned}$ | 95 |  | mA |
|  |  | Sinking to $\mathrm{V}^{+} / 2$ $\mathrm{V}_{\mathrm{ID}}=-200 \mathrm{mV}(\text { Note } 13)$ | $\begin{aligned} & 55 \\ & 40 \end{aligned}$ | 110 |  |  |
| $\mathrm{I}_{\text {OUt }}$ | Output Current | $\mathrm{V}_{\text {OUT }}=0.5 \mathrm{~V}$ from either supply |  | $\pm 65$ |  | mA |
| +PSRR | Positive Power Supply Rejection Ratio | $\mathrm{V}^{+}=3.0 \mathrm{~V}$ to $3.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=1.5 \mathrm{~V}$ | 75 | 85 |  | dB |
| $\mathrm{I}_{\text {S }}$ | Supply Current (per channel) | No Load |  | 2.70 | $\begin{aligned} & 4.00 \\ & 4.50 \end{aligned}$ | mA |

## 5V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for at $T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=5 \mathrm{~V}, \mathrm{~V}^{-}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{O}}=\mathrm{V}^{+} / 2$, and $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$.
Boldface limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | $\begin{gathered} \text { Min } \\ (\text { Note 9) } \end{gathered}$ | $\begin{aligned} & \text { Typ } \\ & \text { (Note 8) } \end{aligned}$ | $\begin{gathered} \text { Max } \\ \text { (Note 9) } \end{gathered}$ | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BW | -3dB BW | $\mathrm{A}_{\mathrm{V}}=+1, \mathrm{~V}_{\text {OUT }}=200 \mathrm{mV} \mathrm{V}_{\text {PP }}$ | 90 | 120 |  | MHz |
|  |  | $A_{V}=+2,-1, V_{\text {OUT }}=200 \mathrm{mV} \mathrm{PPP}$ |  | 46 |  |  |
| $\mathrm{BW}_{0.1 \mathrm{~dB}}$ | 0.1dB Gain Flatness | $\begin{aligned} & A_{V}=+2, R_{L}=150 \Omega \text { to } V+/ 2, \\ & R_{f}=402 \Omega, V_{\text {OUT }}=200 \mathrm{mV}_{\mathrm{PP}} \end{aligned}$ |  | 15 |  | MHz |
| PBW | Full Power Bandwidth | $\mathrm{A}_{\mathrm{V}}=+1,-1 \mathrm{~dB}, \mathrm{~V}_{\text {OUT }}=2 \mathrm{~V}_{\text {PP }}$ |  | 22 |  | MHz |
| $\mathrm{e}_{\mathrm{n}}$ | Input-Referred Voltage Noise | $\mathrm{f}=100 \mathrm{kHz}$ |  | 17 |  | $\mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
|  |  | $\mathrm{f}=1 \mathrm{kHz}$ |  | 48 |  |  |
| $\mathrm{i}_{\mathrm{n}}$ | Input-Referred Current Noise | $\mathrm{f}=100 \mathrm{kHz}$ |  | 0.90 |  | $\mathrm{pA} / \sqrt{\mathrm{Hz}}$ |
|  |  | $\mathrm{f}=1 \mathrm{kHz}$ |  | 3.3 |  |  |
| THD | Total Harmonic Distortion | $\mathrm{f}=5 \mathrm{MHz}, \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}_{\mathrm{PP}}, \mathrm{A}_{\mathrm{V}}=+2$ |  | -60 |  | dBc |
| DG | Differential Gain | $\begin{aligned} & \text { NTSC, } A_{V}=+2 \\ & R_{L}=150 \Omega \text { to } \mathrm{V}^{+} / 2 \end{aligned}$ |  | 0.16 |  | \% |
|  |  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$ |  | 0.05 |  |  |
| DP | Differential Phase | $\begin{aligned} & \text { NTSC, } A_{V}=+2 \\ & R_{L}=150 \Omega \text { to } \mathrm{V}^{+} / 2 \end{aligned}$ |  | 0.05 |  | deg |
|  |  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$ |  | 0.01 |  |  |
| CT Rej. | Cross-Talk Rejection | $\begin{aligned} & f=5 \mathrm{MHz}, \text { Receiver: } \\ & \mathrm{R}_{\mathrm{f}}=\mathrm{R}_{\mathrm{g}}=510 \Omega, \mathrm{~A}_{\mathrm{V}}=+2 \end{aligned}$ |  | 47 |  | dB |
| $\mathrm{T}_{\mathrm{S}}$ | Settling Time | $\mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}_{\mathrm{PP}}, \pm 0.1 \%, 8 \mathrm{pF}$ Load |  | 68 |  | ns |

5V Electrical Characteristics (Continued)
Unless otherwise specified, all limits guaranteed for at $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=5 \mathrm{~V}, \mathrm{~V}^{-}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{O}}=\mathrm{V}^{+} / 2$, and $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$. Boldface limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | $\begin{gathered} \text { Min } \\ (\text { Note } 9) \end{gathered}$ | $\begin{aligned} & \text { Typ } \\ & \text { (Note 8) } \end{aligned}$ | $\begin{gathered} \text { Max } \\ \text { (Note 9) } \end{gathered}$ | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SR | Slew Rate (Note 11) | $\mathrm{A}_{\mathrm{V}}=-1, \mathrm{~V}_{1}=2 \mathrm{~V}_{\mathrm{PP}}$ | 95 | 125 |  | V/us |
| $\mathrm{V}_{\text {OS }}$ | Input Offset Voltage |  |  | $\pm 1$ | $\begin{aligned} & \pm 5 \\ & \pm 7 \end{aligned}$ | mV |
| TC V ${ }_{\text {Os }}$ | Input Offset Average Drift | (Note 15) |  | $\pm 5$ |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | (Note 10) |  | -1.70 | $\begin{aligned} & \hline-2.60 \\ & -3.25 \end{aligned}$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {OS }}$ | Input Offset Current |  |  | 20 | $\begin{gathered} 800 \\ 1000 \end{gathered}$ | nA |
| $\mathrm{R}_{\text {IN }}$ | Common Mode Input Resistance |  |  | 3 |  | $\mathrm{M} \Omega$ |
| $\mathrm{C}_{\text {IN }}$ | Common Mode Input Capacitance |  |  | 2 |  | pF |
| CMVR | Input Common-Mode Voltage Range | CMRR $\geq 50 \mathrm{~dB}$ |  | -0.5 | $\begin{aligned} & -0.2 \\ & -0.1 \end{aligned}$ | V |
|  |  |  | $\begin{aligned} & 3.8 \\ & 3.6 \end{aligned}$ | 4.0 |  |  |
| CMRR | Common Mode Rejection Ratio | $\mathrm{V}_{\mathrm{CM}}$ Stepped from 0V to 3.5V | 72 | 95 |  | dB |
| $\mathrm{A}_{\text {vol }}$ | Large Signal Voltage Gain | $\begin{array}{\|l\|} \hline \mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { to } 4.50 \mathrm{~V} \\ \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega \text { to } \mathrm{V}^{+} / 2 \end{array}$ | $\begin{aligned} & 86 \\ & 82 \end{aligned}$ | 98 |  | dB |
|  |  | $\begin{array}{\|l} \hline \mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V} \text { to } 4.25 \mathrm{~V} \\ \mathrm{R}_{\mathrm{L}}=150 \Omega \text { to } \mathrm{V}^{+} / 2 \\ \hline \end{array}$ | $\begin{aligned} & 76 \\ & 72 \end{aligned}$ | 82 |  |  |
| $\mathrm{V}_{\mathrm{O}}$ | Output Swing High | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2, \mathrm{~V}_{\mathrm{ID}}=200 \mathrm{mV}$ | 4.90 | 4.98 |  | V |
|  |  | $\mathrm{R}_{\mathrm{L}}=150 \Omega$ to $\mathrm{V}^{+} / 2, \mathrm{~V}_{\text {ID }}=200 \mathrm{mV}$ | 4.65 | 4.90 |  |  |
|  | Output Swing Low | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2, \mathrm{~V}_{\text {ID }}=-200 \mathrm{mV}$ |  | 25 | 100 | mV |
|  |  | $\mathrm{R}_{\mathrm{L}}=150 \Omega$ to $\mathrm{V}^{+} / 2, \mathrm{~V}_{\mathrm{ID}}=-200 \mathrm{mV}$ |  | 100 | 150 |  |
| $\mathrm{I}_{\mathrm{sc}}$ | Output Short Circuit Current | Sourcing to $\mathrm{V}^{+} / 2$ $\mathrm{V}_{\mathrm{ID}}=200 \mathrm{mV} \text { (Note } 13 \text { ) }$ | $\begin{aligned} & 55 \\ & 40 \\ & \hline \end{aligned}$ | 115 |  | mA |
|  |  | Sinking to $\mathrm{V}^{+} / 2$ $\mathrm{V}_{\mathrm{ID}}=-200 \mathrm{mV}(\text { Note } 13)$ | $\begin{aligned} & 70 \\ & 55 \end{aligned}$ | 140 |  |  |
| $\mathrm{I}_{\text {OUT }}$ | Output Current | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ from either supply |  | $\pm 70$ |  | mA |
| +PSRR | Positive Power Supply Rejection Ratio | $\mathrm{V}^{+}=4.0 \mathrm{~V}$ to 6 V | 79 | 90 |  | dB |
| $I_{s}$ | Supply Current (per channel) | No Load |  | 2.70 | $\begin{aligned} & 4.25 \\ & 5.00 \end{aligned}$ | mA |

## $\pm 5 \mathrm{~V}$ Electrical Characteristics

Unless otherwise specified, all limits guaranteed for at $T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=5 \mathrm{~V}, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{O}}=0 \mathrm{~V}$ and $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to ground. Boldface limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | $\begin{gathered} \text { Min } \\ (\text { Note 9) } \end{gathered}$ | $\begin{gathered} \text { Typ } \\ \text { (Note 8) } \end{gathered}$ | $\begin{gathered} \text { Max } \\ \text { (Note 9) } \end{gathered}$ | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BW | -3dB BW | $\mathrm{A}_{\mathrm{V}}=+1, \mathrm{~V}_{\text {OUT }}=200 \mathrm{mV} \mathrm{VPP}$ | 95 | 130 |  | MHz |
|  |  | $\mathrm{A}_{\mathrm{V}}=+2,-1, \mathrm{~V}_{\text {OUT }}=200 \mathrm{mV} \mathrm{PPP}$ |  | 46 |  |  |
| $B W_{0.1 d B}$ | 0.1dB Gain Flatness | $\begin{aligned} & A_{V}=+2, R_{L}=150 \Omega \text { to } V+/ 2, \\ & R_{f}=806 \Omega, V_{\text {OUT }}=200 \mathrm{mV}_{\mathrm{PP}} \end{aligned}$ |  | 12 |  | MHz |
| PBW | Full Power Bandwidth | $\mathrm{A}_{\mathrm{V}}=+1,-1 \mathrm{~dB}, \mathrm{~V}_{\text {OUT }}=2 \mathrm{~V}_{\text {PP }}$ |  | 24 |  | MHz |
| $\mathrm{e}_{\mathrm{n}}$ | Input-Referred Voltage Noise | $\mathrm{f}=100 \mathrm{kHz}$ |  | 17 |  | $\mathrm{nV} / \sqrt{\mathrm{Hz}}$ |
|  |  | $\mathrm{f}=1 \mathrm{kHz}$ |  | 48 |  |  |

## $\pm 5 \mathrm{~V}$ Electrical Characteristics (Continued)

Unless otherwise specified, all limits guaranteed for at $T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=5 \mathrm{~V}, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{~V}_{\mathrm{CM}}=\mathrm{V}_{\mathrm{O}}=0 \mathrm{~V}$ and $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$ to ground. Boldface limits apply at the temperature extremes.

| Symbol | Parameter | Conditions | Min (Note 9) | Typ (Note 8) | $\begin{gathered} \text { Max } \\ \text { (Note 9) } \end{gathered}$ | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $i_{n}$ | Input-Referred Current Noise | $\mathrm{f}=100 \mathrm{kHz}$ |  | 0.90 |  | $\mathrm{pA} / \sqrt{\mathrm{Hz}}$ |
|  |  | $\mathrm{f}=1 \mathrm{kHz}$ |  | 3.3 |  |  |
| THD | Total Harmonic Distortion | $\mathrm{f}=5 \mathrm{MHz}, \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}_{\mathrm{PP}}, \mathrm{A}_{\mathrm{V}}=+2$ |  | -62 |  | dBc |
| DG | Differential Gain | $\begin{aligned} & \hline \text { NTSC, } A_{\mathrm{V}}=+2 \\ & \mathrm{R}_{\mathrm{L}}=150 \Omega \text { to } \mathrm{V}^{+} / 2 \\ & \hline \end{aligned}$ |  | 0.15 |  | \% |
|  |  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$ |  | 0.01 |  |  |
| DP | Differential Phase | $\begin{aligned} & \hline \text { NTSC, } A_{V}=+2 \\ & R_{L}=150 \Omega \text { to } \mathrm{V}^{+} / 2 \\ & \hline \end{aligned}$ |  | 0.04 |  | deg |
|  |  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to $\mathrm{V}^{+} / 2$ |  | 0.01 |  |  |
| CT Rej. | Cross-Talk Rejection | $\begin{aligned} & \hline \mathrm{f}=5 \mathrm{MHz}, \text { Receiver: } \\ & \mathrm{R}_{\mathrm{f}}=\mathrm{R}_{\mathrm{g}}=510 \Omega, \mathrm{~A}_{\mathrm{V}}=+2 \\ & \hline \end{aligned}$ |  | 47 |  | dB |
| $\mathrm{T}_{\text {S }}$ | Settling Time | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}=2 \mathrm{~V}_{\mathrm{PP}}, \pm 0.1 \%, 8 \mathrm{pF} \text { Load, } \\ & \mathrm{V}_{\mathrm{S}}=5 \mathrm{~V} \end{aligned}$ |  | 68 |  | ns |
| SR | Slew Rate (Note 11) | $\mathrm{A}_{\mathrm{V}}=-1, \mathrm{~V}_{1}=2 \mathrm{~V}_{\mathrm{PP}}$ | 100 | 135 |  | V/ $/$ s |
| $\mathrm{V}_{\text {OS }}$ | Input Offset Voltage |  |  | $\pm 1$ | $\begin{aligned} & \pm 5 \\ & \pm 7 \end{aligned}$ | mV |
| TC V ${ }_{\text {Os }}$ | Input Offset Average Drift | (Note 15) |  | $\pm 5$ |  | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{B}}$ | Input Bias Current | (Note 10) |  | -1.60 | $\begin{aligned} & \hline-2.60 \\ & -3.25 \end{aligned}$ | $\mu \mathrm{A}$ |
| $\mathrm{l}_{\mathrm{os}}$ | Input Offset Current |  |  | 20 | $\begin{gathered} \hline 800 \\ 1000 \end{gathered}$ | nA |
| $\mathrm{R}_{\text {IN }}$ | Common Mode Input Resistance |  |  | 3 |  | $\mathrm{M} \Omega$ |
| $\mathrm{Cl}_{\text {IN }}$ | Common Mode Input Capacitance |  |  | 2 |  | pF |
| CMVR | Input Common-Mode Voltage Range | CMRR $\geq 50 \mathrm{~dB}$ |  | -5.5 | $\begin{aligned} & \hline-5.2 \\ & -5.1 \end{aligned}$ | V |
|  |  |  | $\begin{aligned} & 3.8 \\ & 3.6 \end{aligned}$ | 4.0 |  |  |
| CMRR | Common Mode Rejection Ratio | $\mathrm{V}_{\mathrm{CM}}$ Stepped from -5V to 3.5V | 74 | 95 |  | dB |
| $\mathrm{A}_{\text {VOL }}$ | Large Signal Voltage Gain | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}=-4.5 \mathrm{~V} \text { to } 4.5 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega \\ & \hline \end{aligned}$ | $\begin{aligned} & \hline 88 \\ & 84 \end{aligned}$ | 96 |  | dB |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{O}}=-4.0 \mathrm{~V} \text { to } 4.0 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=150 \Omega \end{aligned}$ | $\begin{aligned} & 78 \\ & 74 \\ & \hline \end{aligned}$ | 82 |  |  |
| $\mathrm{V}_{\text {O }}$ | Output Swing High | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{V}_{\mathrm{ID}}=200 \mathrm{mV}$ | 4.90 | 4.96 |  | V |
|  |  | $\mathrm{R}_{\mathrm{L}}=150 \Omega, \mathrm{~V}_{\text {ID }}=200 \mathrm{mV}$ | 4.65 | 4.80 |  |  |
|  | Output Swing Low | $\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{V}_{\text {ID }}=-200 \mathrm{mV}$ |  | -4.96 | -4.90 | V |
|  |  | $\mathrm{R}_{\mathrm{L}}=150 \Omega, \mathrm{~V}_{\text {ID }}=-200 \mathrm{mV}$ |  | -4.80 | -4.65 |  |
| $I_{\text {sc }}$ | Output Short Circuit Current | Sourcing to Ground $\mathrm{V}_{\mathrm{ID}}=200 \mathrm{mV} \text { (Note 13) }$ | $\begin{aligned} & 60 \\ & 35 \\ & \hline \end{aligned}$ | 115 |  | mA |
|  |  | Sinking to Ground $\mathrm{V}_{\mathrm{ID}}=-200 \mathrm{mV}$ (Note 13) | $\begin{aligned} & 85 \\ & 65 \end{aligned}$ | 145 |  |  |
| $\mathrm{I}_{\text {OUT }}$ | Output Current | $\mathrm{V}_{\mathrm{O}}=0.5 \mathrm{~V}$ from either supply | $\pm 75$ |  |  | mA |
| PSRR | Power Supply Rejection Ratio | $\begin{aligned} & \left(\mathrm{V}^{+}, \mathrm{V}^{-}\right)=(4.5 \mathrm{~V},-4.5 \mathrm{~V}) \text { to }(5.5 \mathrm{~V}, \\ & -5.5 \mathrm{~V}) \end{aligned}$ | 78 | 90 |  | dB |
| $\mathrm{I}_{\text {S }}$ | Supply Current (per channel) | No Load |  | 2.70 | $\begin{aligned} & 4.50 \\ & 5.50 \end{aligned}$ | mA |

## $\pm 5 \mathrm{~V}$ Electrical Characteristics (Continued)

Note 4: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.
Note 5: Human body model, $1.5 \mathrm{k} \Omega$ in series with 100 pF .
Note 6: Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of $150^{\circ} \mathrm{C}$.
Note 7: The maximum power dissipation is a function of $T_{J(M A X)}, \theta_{J A}$, and $T_{A}$. The maximum allowable power dissipation at any ambient temperature is $P_{D}=\left(T_{J(M A X)}-T_{A}\right) / \theta_{J A}$. All numbers apply for packages soldered directly onto a PC board.
Note 8: Typical values represent the most likely parametric norm.
Note 9: All limits are guaranteed by testing or statistical analysis.
Note 10: Positive current corresponds to current flowing into the device.
Note 11: Slew rate is the average of the rising and falling slew rates.
Note 12: Machine Model, $0 \Omega$ in series with 200 pF .
Note 13: Short circuit test is a momentary test. See Note 14.
Note 14: Output short circuit duration is infinite for $\mathrm{V}_{\mathrm{S}}<6 \mathrm{~V}$ at room temperature and below. For $\mathrm{V}_{\mathrm{S}}>6 \mathrm{~V}$, allowable short circuit duration is 1.5 ms .
Note 15: Offset voltage average drift determined by dividing the change in $\mathrm{V}_{\mathrm{OS}}$ at temperature extremes by the total temperature change.

## Connection Diagrams



Typical Performance Characteristics erwise specified.

Closed Loop Frequency Response for Various Supplies


20089457

Closed Loop Gain vs. Frequency for Various Gain


Closed Loop Gain vs. Frequency for Various Supplies


Closed Loop Gain vs. Frequency for Various Gain


20089451
Closed Loop Frequency Response for Various Temperature


20089450

Closed Loop Frequency Response for Various Temperature


Typical Performance Characteristics $A t \mathrm{~T}_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=+5, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$. Unless otherwise specified. (Continued)

Large Signal Frequency Response


20089447
Closed Loop Frequency Response for Various Supplies


20089444


Closed Loop Small Signal Frequency Response for Various Supplies


20089446


20089445


20089408

Typical Performance Characteristics $A t T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=+5, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$. Unless otherwise specified. (Continued)


20089410
Open Loop Gain/Phase for Various Temperature


20089433


20089415


20089432
HD2 (dBc) vs. Output Swing


20089414
HD2 vs. Output Swing


LMH6642EP/LMH6643EP/LMH6644EP Enhanced Plastic
Typical Performance Characteristics $A t T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=+5, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{R}_{F}=\mathrm{R}_{\mathrm{L}}=2 \mathrm{~K} \Omega$. Unless otherwise specified. (Continued)


20089405
Settling Time vs. Input Step Amplitude (Output Slew and Settle Time)


20089413


20089418

THD (dBc) vs. Output Swing


20089406

Input Noise vs. Frequency


20089412

Typical Performance Characteristics $A t T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=+5, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$. Unless otherwise specified. (Continued)


20089416
Swing vs. $\mathbf{V}_{\mathbf{S}}$


20089429
Output Sinking Saturation Voltage vs. I Iut


20089420


20089417
Short Circuit Current (to $\mathrm{V}_{\mathrm{S}} / 2$ ) vs. $\mathrm{V}_{\mathrm{S}}$


20089431
Output Sourcing Saturation Voltage vs. I IOUT


Typical Performance Characteristics $\mathrm{At}_{\mathrm{T}}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=+5, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$. Unless otherwise specified. (Continued)

Closed Loop Output Impedance vs. Frequency $\mathrm{A}_{\mathrm{V}}=\boldsymbol{+ 1}$


20089402

CMRR vs. Frequency


20089407
$\mathrm{V}_{\text {os }}$ vs. $\mathrm{V}_{\text {Out }}$ (Typical Unit)


20089430

PSRR vs. Frequency


20089403
Crosstalk Rejection vs. Frequency (Output to Output)


20089411

Typical Performance Characteristics $A t T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=+5, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$. Unless otherwise specified. (Continued)
$\mathbf{V}_{\text {os }}$ vs. $\mathbf{V}_{\mathbf{S}}$ (for 3 Representative Units)

$\mathbf{V}_{\mathrm{Os}}$ vs. $\mathbf{V}_{\mathbf{S}}$ (for 3 Representative Units)


20089424
$l_{\text {os }}$ vs. $\mathrm{V}_{\mathrm{s}}$



20089423
$I_{B}$ vs. $V_{S}$


20089425
$I_{s}$ vs. $V_{C M}$


Typical Performance Characteristics $A t T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=+5, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{R}_{F}=\mathrm{R}_{\mathrm{L}}=2 \mathrm{~K} \Omega$. Unless otherwise specified. (Continued)


20089421

## Large Signal Step Response



## Small Signal Step Response



Small Signal Step Response


Large Signal Step Response


Small Signal Step Response


Typical Performance Characteristics $A t T_{J}=25^{\circ} \mathrm{C}, \mathrm{V}^{+}=+5, \mathrm{~V}^{-}=-5 \mathrm{~V}, \mathrm{R}_{\mathrm{F}}=\mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega$. Unless otherwise specified. (Continued)


Small Signal Step Response


Large Signal Step Response


## Application Notes

## CIRCUIT DESCRIPTION

The LMH664XEP family is based on National Semiconductor's proprietary VIP10 dielectrically isolated bipolar process.
This device family architecture features the following:

- Complimentary bipolar devices with exceptionally high $f_{t}$ $(\sim 8 \mathrm{GHz})$ even under low supply voltage ( 2.7 V ) and low bias current
- A class A-B "turn-around" stage with improved noise, offset, and reduced power dissipation compared to similar speed devices (patent pending).
- Common Emitter push-push output stage capable of 75 mA output current (at 0.5 V from the supply rails) while consuming only 2.7 mA of total supply current per channel. This architecture allows output to reach within millivolts of either supply rail.
- Consistent performance from any supply voltage (3V10 V ) with little variation with supply voltage for the most important specifications (e.g. BW, SR, I Iout, etc.)
- Significant power saving ( $\sim 40 \%$ ) compared to competitive devices on the market with similar performance.


## Application Hints

This Op Amp family is a drop-in replacement for the AD805X family of high speed Op Amps in most applications. In addition, the LMH664XEP will typically save about $40 \%$ on power dissipation, due to lower supply current, when compared to competition. All AD805X family's guaranteed parameters are included in the list of LMH664XEP guaranteed specifications in order to ensure equal or better level of performance. However, as in most high performance parts, due to subtleties of applications, it is strongly recommended that the performance of the part to be evaluated is tested under actual operating conditions to ensure full compliance to all specifications.
With 3 V supplies and a common mode input voltage range that extends 0.5 V below $\mathrm{V}^{-}$, the LMH664XEP find applications in low voltage/low power applications. Even with 3 V supplies, the -3 dB BW ( $@ A_{V}=+1$ ) is typically 115 MHz with a tested limit of 80 MHz . Production testing guarantees that process variations with not compromise speed. High frequency response is exceptionally stable confining the typical -3 dB BW over the industrial temperature range to $\pm 2.5 \%$.
As can be seen from the typical performance plots, the LMH664XEP output current capability ( $\sim 75 \mathrm{~mA}$ ) is enhanced compared to AD805X. This enhancement, increases the output load range, adding to the LMH664XEP's versatility.
Because of the LMH664XEP's high output current capability attention should be given to device junction temperature in order not to exceed the Absolute Maximum Rating.

This device family was designed to avoid output phase reversal. With input overdrive, the output is kept near supply rail (or as closed to it as mandated by the closed loop gain setting and the input voltage). See Figure 1:


FIGURE 1. Input and Output Shown with CMVR Exceeded

However, if the input voltage range of -0.5 V to 1 V from $\mathrm{V}^{+}$is exceeded by more than a diode drop, the internal ESD protection diodes will start to conduct.The current in the diodes should be kept at or below 10 mA .
Output overdrive recovery time is less than 100 ns as can be seen from Figure 2 plot:


FIGURE 2. Overload Recovery Waveform

## Application Notes

(Continued)

## SINGLE SUPPLY, LOW POWER PHOTODIODE AMPLIFIER

The circuit shown in Figure 3 is used to amplify the current from a photo-diode into a voltage output. In this circuit, the emphasis is on achieving high bandwidth and the transimpedance gain setting is kept relatively low. Because of its high slew rate limit and high speed, the LMH664XEP family lends itself well to such an application.
This circuit achieves approximately $1 \mathrm{~V} / \mathrm{mA}$ of transimpedance gain and capable of handling up to $1 \mathrm{~mA}_{\mathrm{pp}}$ from the photodiode. Q1, in a common base configuration, isolates the high capacitance of the photodiode $\left(\mathrm{C}_{\mathrm{d}}\right)$ from the Op Amp input in order to maximize speed. Input is AC coupled through C1 to ease biasing and allow single supply operation. With 5 V single supply, the device input/output is shifted to near half supply using a voltage divider from $\mathrm{V}_{\mathrm{CC}}$. Note that Q1 collector does not have any voltage swing and the Miller effect is minimized. D1, tied to Q1 base, is for temperature compensation of Q1's bias point. Q1 collector current was set to be large enough to handle the peak-to-peak photodiode excitation and not too large to shift the U1 output too far from mid-supply.
No matter how low an $R_{f}$ is selected, there is a need for $C_{f}$ in order to stabilize the circuit. The reason for this is that the Op

Amp input capacitance and Q1 equivalent collector capacitance together $\left(\mathrm{C}_{\mathrm{IN}}\right)$ will cause additional phase shift to the signal fed back to the inverting node. $\mathrm{C}_{f}$ will function as a zero in the feedback path counter-acting the effect of the $\mathrm{C}_{\mathrm{IN}}$ and acting to stabilized the circuit. By proper selection of $\mathrm{C}_{\mathrm{f}}$ such that the Op Amp open loop gain is equal to the inverse of the feedback factor at that frequency, the response is optimized with a theoretical $45^{\circ}$ phase margin.

$$
\begin{equation*}
\mathrm{C}_{\mathrm{F}}=\sim \operatorname{SQRT}\left[\left(\mathrm{C}_{\mathbb{N}}\right) /\left(2 \pi \cdot \mathrm{GBWP} \cdot \mathrm{R}_{\mathrm{F}}\right)\right] \tag{1}
\end{equation*}
$$

where GBWP is the Gain Bandwidth Product of the Op Amp Optimized as such, the I-V converter will have a theoretical pole, $\mathrm{f}_{\mathrm{p}}$, at:

$$
\begin{equation*}
\mathrm{f}_{\mathrm{P}}=\mathrm{SQRT}\left[\mathrm{GBWP} /\left(2 \pi \mathrm{R}_{\mathrm{F}} \cdot \mathrm{C}_{\mathbb{N}}\right)\right] \tag{2}
\end{equation*}
$$

With Op Amp input capacitance of 3pF and an estimate for Q1 output capacitance of about 3 pF as well, $\mathrm{C}_{\mathrm{IN}}=6 \mathrm{pF}$. From the typical performance plots, LMH6642EP/6643EP family GBWP is approximately 57 MHz . Therefore, with $\mathrm{R}_{\mathrm{f}}=1 \mathrm{k}$, from Equation 1 and 2 above.
$C_{f}=\sim 4.1 \mathrm{pF}$, and $\mathrm{f}_{\mathrm{p}}=39 \mathrm{MHz}$


FIGURE 3. Single Supply Photodiode I-V Converter

## Application Notes (Continued)

For this example, optimum $C_{f}$ was empirically determined to be around 5 pF . This time domain response is shown in Figure 4 below showing about 9 ns rise/fall times, corresponding to about 39 MHz for $\mathrm{f}_{\mathrm{p}}$. The overall supply current from the +5 V supply is around 5 mA with no load.


FIGURE 4. Converter Step Response ( $1 \mathrm{~V}_{\mathrm{PP}}, 20 \mathrm{~ns} / \mathrm{DIV}$ )

PRINTED CIRCUIT BOARD LAYOUT AND COMPONENT VALUES SECTIONS
Generally, a good high frequency layout will keep power supply and ground traces away from the inverting input and
output pins. Parasitic capacitances on these nodes to ground will cause frequency response peaking and possible circuit oscillations (see Application Note OA-15 for more information). National Semiconductor suggests the following evaluation boards as a guide for high frequency layout and as an aid in device testing and characterization:

| Device | Package | Evaluation <br> Board PN |
| :---: | :---: | :---: |
| LMH6642MF | SOT23-5 | CLC730068 |
| LMH6642MF | 8-Pin SOIC | CLC730027 |
| LMH6643MA | 8-Pin SOIC | CLC730036 |
| LMH6643MA | 8-Pin MSOP | CLC730123 |
| LMH6644MA | 14-Pin SOIC | CLC730031 |
| LMH6644MA | 14-Pin TSSOP | CLC730131 |

These free evaluation boards are shipped when a device sample request is placed with National Semiconductor.
Another important parameter in working with high speed/ high performance amplifiers, is the component values selection. Choosing external resistors that are large in value will effect the closed loop behavior of the stage because of the interaction of these resistors with parasitic capacitances. These capacitors could be inherent to the device or a byproduct of the board layout and component placement. Either way, keeping the resistor values lower, will diminish this interaction to a large extent. On the other hand, choosing very low value resistors could load down nodes and will contribute to higher overall power dissipation.

Physical Dimensions inches (millimeters) unless otherwise noted



Physical Dimensions inches (millimeters) unless otherwise noted (Continued)


CONTROLLING DIMENSION IS INCH
VALUES IN | | ARE MILLIMETERS
M14A (Rev J)

14-Pin SOIC
NS Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)


## LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

## BANNED SUBSTANCE COMPLIANCE

National Semiconductor certifies that the products and packing materials meet the provisions of the Customer Products Stewardship Specification (CSP-9-111C2) and the Banned Substances and Materials of Interest Specification (CSP-9-111S2) and contain no "Banned Substances" as defined in CSP-9-111S2.

| National Semiconductor | National Semiconductor | National Semiconductor | National Semiconductor |
| :---: | :---: | :---: | :---: |
| Americas Customer | Europe Customer Support Center | Asia Pacific Customer | Japan Customer Support Center |
| Support Center | Fax: +49 (0) 180-530 8586 | Support Center | Fax: 81-3-5639-7507 |
| Email: new.feedback@nsc.com | Email: europe.support@nsc.com | Email: ap.support@nsc.com | Email: jpn.feedback@nsc.com |
| Tel: 1-800-272-9959 | Deutsch Tel: +49 (0) 6995086208 |  | Tel: 81-3-5639-7560 |
|  | English Tel: +44 (0) 8702402171 |  |  |
| www.national.com | Français Tel: +33 (0) 141918790 |  |  |

Français Tel: + +3

National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications

